

Claims

1. A method for error correction decoding ECC encoded data stored in a solid-state storage device having a plurality of storage cells, comprising the steps of:

obtaining parametric values from a set of the storage cells;

- generating a block of stored ECC encoded data, using the obtained parametric values;

- forming erasure information for the block of stored ECC encoded data, using the obtained parametric values; and

error correction decoding the block of stored ECC encoded data with reference to the erasure information.

2. The method of claim 1, comprising reading the set of storage cells.

3. The method of claim 1, comprising generating logical values with respect to the obtained parametric values.

4. The method of claim 1, comprising comparing the obtained parametric values against a range.

5. The method of claim 1, wherein the device is a magnetoresistive solid-state storage device.

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12. The method of claim 8, wherein the decoding step comprises identifying the location of zero or more failed symbols in the block of encoded data, using the erasure information; and replacing each identified failed symbol
5 with a calculated correct value.

13. The method of claim 1, comprising the step of writing back corrected encoded data to the storage cells.

10 14. The method of claim 13, wherein the write-back step comprises selectively writing back corrected encoded data to the storage cells, with reference to the erasure information.

15 15. The method of claim 14, wherein the write-back step comprises selectively not writing back corrected encoded data to storage cells which are determined as affected by physical failures.

20 16. The method of claim 1, further comprising the steps of:

encoding a logical unit of original information to form a block of ECC encoded data; and

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storing the block of ECC encoded data in the array of storage cells;

30 wherein the decoding step attempts to recover the logical unit of original information from the stored block of ECC encoded data.

17. A solid state storage device, comprising:

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at least one array of storage cells; and

an array controller for obtaining parametric values
5 from a set of the storage cells and generating a block of
stored ECC encoded data using the obtained parametric
values, including forming erasure information for the
block of stored ECC encoded data using the obtained
parametric values; and

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an ECC decoding unit for decoding the block of stored
ECC encoded data with reference to the erasure
information.

15 18. The device of claim 1, wherein the device is a
magnetoresistive solid-state storage device.

19. A magnetoresistive solid-state storage device,
comprising:

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at least one array of magnetoresistive storage cells;

an ECC coding unit for receiving original information
and forming a block of ECC encoded data;

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a controller for storing the block of ECC encoded data
in the array of storage cells;

an array controller for obtaining parametric values
30 from a set of the storage cells and generating a block of
stored ECC encoded data using the obtained parametric
values, including forming erasure information for the

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block of stored ECC encoded data using the obtained parametric values; and

an ECC decoding unit for decoding the block of stored
5 ECC encoded data with reference to the erasure information.

20. An apparatus incorporating a magnetoresistive storage device according to claim 19.

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